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April 2001

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FAIRCHILD

FDC6310P Dual P-Channel 2.5V Specified PowerTrench[®] MOSFET

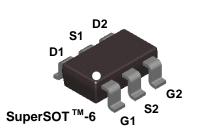
General Description

These P-Channel 2.5V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain low gate charge for superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive SO-8 and TSSOP-8 packages are impractical.

Applications

- Load switch
- Battery protection
- Power management



• -2.2 A, -20 V. $R_{DS(ON)}$ = 125 m Ω @ V_{GS} = -4.5 V

High performance trench technology for extremely

 SuperSOT TM -6 package: small footprint 72% smaller than standard SO-8); low profile (1mm thick)

 $R_{DS(ON)} = 190 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$

Features

· Low gate charge

low RDS(ON)

· Fast switching speed

Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Sourc	e Voltage		-20	
V _{GSS}	Gate-Source Voltage			±12	
l _D	Drain Curre	nt – Continuous	(Note 1a)	-2.2	A
		– Pulsed		-6	
PD	Power Dissipation for Single Operation		(Note 1a)	0.96	W
			(Note 1b)	0.9	
			(Note 1c)	0.7	
T_J, T_{STG}	Operating a	erating and Storage Junction Temperature Range		-55 to +150	°C
Therma	I Charact	eristics			
$R_{\theta JA}$	Thermal Re	sistance, Junction-to-Ambie	ent (Note 1a)	130	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		(Note 1)	60	°C/W
Packag	e Marking	g and Ordering In	formation		
Device Marking		Device	Reel Size	Tape width	Quantity
.310		FDC6310P	7"	8mm 3000 u	

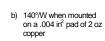
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FDC6310P Rev C(W)

FDC6310P

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	I				
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
$\Delta BV_{DSS} \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-11		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$, $V_{GS} = 0 V$			-1	μA
GSSF	Gate-Body Leakage, Forward	$V_{GS} = 12 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = -12 V$, $V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)			•		
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.6	-1.0	-1.5	V
<u>ΔVgs(th)</u> ΔTj	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source	$V_{GS} = -4.5 \text{ V}, I_D = -2.2 \text{ A}$		100	125	mΩ
	On–Resistance	$V_{GS} = -2.5 \text{ V}, I_D = -1.8 \text{ A}$		145	190	
	On Otata Durin Orimont	V_{GS} =-4.5 V, I _D =-2.2 A, T _J =125°C V _{GS} = -4.5 V, V _{DS} = -5 V	0	137	184	•
D(on)	On–State Drain Current		-6	0		A
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_{D} = -3.5 A$		6		S
	Characteristics		1	227		~ Г
C _{iss}	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$, f = 1.0 MHz		337		pF
Coss	Output Capacitance Reverse Transfer Capacitance			88 51		pF pF
Crss				51		рг
	g Characteristics (Note 2)		1		4.0	
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -10 V$, $I_D = -1 A$, $V_{GS} = -4.5 V$, $R_{GEN} = 6 \Omega$		9	18	ns
t _r	Turn–On Rise Time	$V_{\rm GS} = -4.5 V$, $V_{\rm GEN} = 0.22$		12	22	ns
t _{d(off)}	Turn-Off Delay Time	-		10	20	ns
t _f	Turn–Off Fall Time	$V_{DS} = -10 V$, $I_D = -2.2 A$,		5	10	ns
Q _g Q _{gs}	Total Gate Charge Gate–Source Charge	$V_{DS} = -10 V$, $I_D = -2.2 A$, $V_{GS} = -4.5 V$		3.7 0.65	5.2	nC nC
-	Gate–Drain Charge			1.3		nC
Q _{gd}	Ğ	n d Mariana Datin na		1.5		lic
	ource Diode Characteristics		1	1		
ls	Maximum Continuous Drain–Source Diode Forward Current				-0.8	A
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -0.8 A$ (Note 2)		0.77	-1.2	V

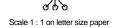




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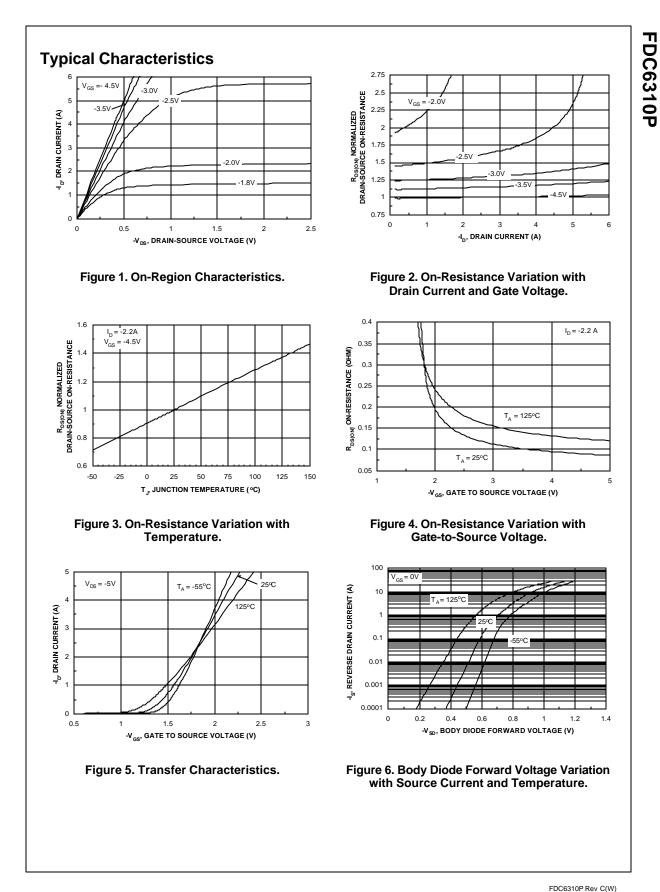
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c) 180°/W when mounted on a minimum pad.

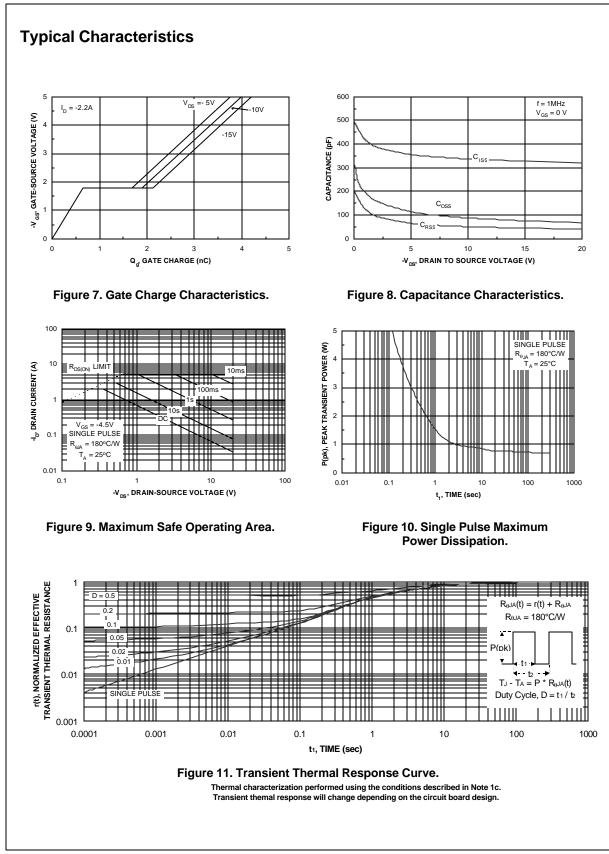


2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty Cycle < 2.0%

FDC6310P Rev C(W)



FDC6310P Rev C(\



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